

CLL914
HIGH SPEED
SWITCHING DIODE



SOD-80 CASE

CentralTM

Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CLL914 type is an ultra-high speed silicon switching diode manufactured by the epitaxial planar process, in a hermetically sealed glass surface mount package, designed for high speed switching applications.

MARKING CODE: CATHODE BAND.

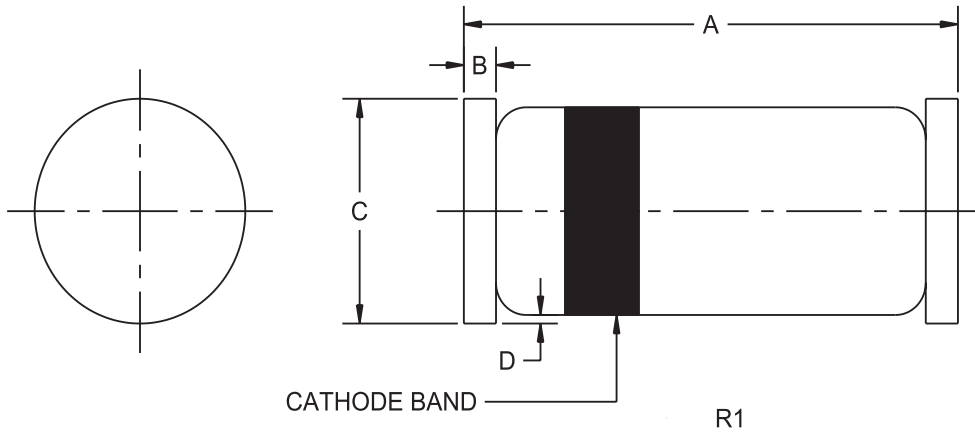
MAXIMUM RATINGS ($T_A=25^\circ\text{C}$)

	SYMBOL		UNITS
Continuous Reverse Voltage	V_R	75	V
Peak Repetitive Reverse Voltage	V_{RRM}	100	V
Continuous Forward Current	I_F	250	mA
Peak Repetitive Forward Current	I_{FRM}	250	mA
Forward Surge Current, $t_p=1 \mu\text{s}$	I_{FSM}	4.0	A
Forward Surge Current, $t_p=1 \text{ s}$	I_{FSM}	1.0	A
Power Dissipation	P_D	500	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$
Thermal Resistance	θ_{JA}	350	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
BV_R	$I_R=100\mu\text{A}$	100		V
I_R	$V_R=20\text{V}$		25	nA
I_R	$V_R=75\text{V}$		5.0	μA
V_F	$I_F=10\text{mA}$		1.0	V
C_T	$V_R=0, f=1 \text{ MHz}$		4.0	pF
t_{rr}	$I_R=I_F=10\text{mA}, R_L=100\Omega, \text{Rec. to } 1.0\text{mA}$		4.0	ns

SOD-80 CASE - MECHANICAL OUTLINE



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SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.130	0.146	3.30	3.71
B	0.016		0.41	
C (DIA)	0.051	0.067	1.30	1.70
D	-	0.004	-	0.10

SOD-80 (REV:R1)

R1 (26-September 2002)